

## ABSTRACT OF THE DISCLOSURE

There is disclosed a piezoelectric/electrostrictive film type device which has a flexural displacement and durability equal to or more than those of a prior art piezoelectric/electrostrictive film type device and which has a remarkably high resonance frequency and which is superior in high-speed response. The piezoelectric/electrostrictive film type device comprises: a substrate formed of ceramic; and a piezoelectric/electrostrictive operation portion including a lower electrode, piezoelectric/electrostrictive layer, and upper electrode which are successively stacked on the substrate and including a projecting end of the piezoelectric/electrostrictive layer with which an upper surface of the lower electrode and a lower surface of the upper electrode are coated, and a projecting portion of the piezoelectric/electrostrictive layer is a connecting material constituted of a hybrid material in which inorganic particles are scattered in a matrix of a polymer compound, and is connected to the substrate.